



**THE DATASHEET OF  
NCP2811AMTTXGEVB**



# NCP2811

## NOCAP™ Advanced Stereo Headphone Amplifier

NCP2811 is a dual audio power amplifier designed for portable communication device applications such as mobile phones. This part is capable of delivering 27 mW of continuous average power into a 16 Ω load from a 2.7 V power supply with a THD+N of 1%.

Based on the power supply delivered to the device, an internal power management block generates a symmetrical positive and negative voltage. Thus, the internal amplifiers provide outputs referenced to Ground. In this True Ground configuration, the two external heavy coupling capacitors can be removed. It offers significant space and cost savings compared to a typical stereo application.

NCP2811 is available with an external adjustable gain (version A), or with an internal gain of -1.5 V/V (version B). It reaches a superior -100 dB PSRR and noise floor. Thus, it offers high fidelity audio sound, as well as a direct connection to the battery. It contains circuitry to prevent from “Pop & Click” noise that would otherwise occur during turn-on and turn-off transitions. The device is available in 12 bump CSP package (2 x 1.5 mm) which help to save space on the board. It is also available in WQFN12 and TSSOP-14 packages.

### Features

- True Ground Configuration Output Eliminates DC-Blocking Capacitors:
  - Save Board Area
  - Save Component Cost
  - No Low-Frequency Response Attenuation
- High PSRR (-100 dB): Direct Connection to the Battery
- “Pop and Click” Noise Protection Circuitry
- Internal Gain (-1.5 V/V) or External Adjustable Gain
- Ultra Low Current Shutdown Mode
- 2.7 V – 5.0 V Operation
- Thermal Overload Protection Circuitry
- CSP 2 x 1.5 mm
- WQFN12 3 x 3 mm
- TSSOP-14
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### Typical Applications

- Headset Audio Amplifier for
  - Cellular Phones
  - MP3 Player
  - Personal Digital Assistant and Portable Media Player
  - Portable Devices



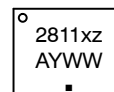
ON Semiconductor®

<http://onsemi.com>

### MARKING DIAGRAMS



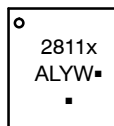
12 PIN CSP  
FC SUFFIX  
CASE 499AZ



- x = A for NCP2811A
- = B for NCP2811B
- z = C for backside laminate
- A = Assembly Location
- Y = Year
- WW = Work Week
- = Pb-Free Package

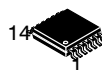


WQFN12  
MT SUFFIX  
CASE 510AH

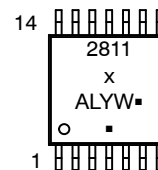


- x = A for NCP2811A
- = B for NCP2811B
- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)



TSSOP-14  
DTB SUFFIX  
CASE 948G



- x = A for NCP2811A
- = B for NCP2811B
- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information on page 12 of this data sheet.

# NCP2811

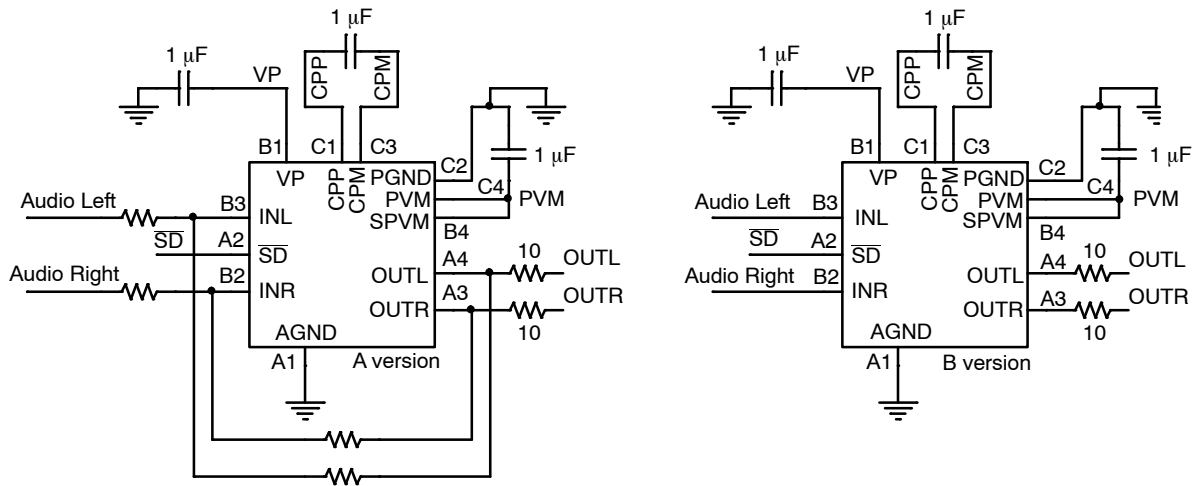


Figure 1. Application Schematics

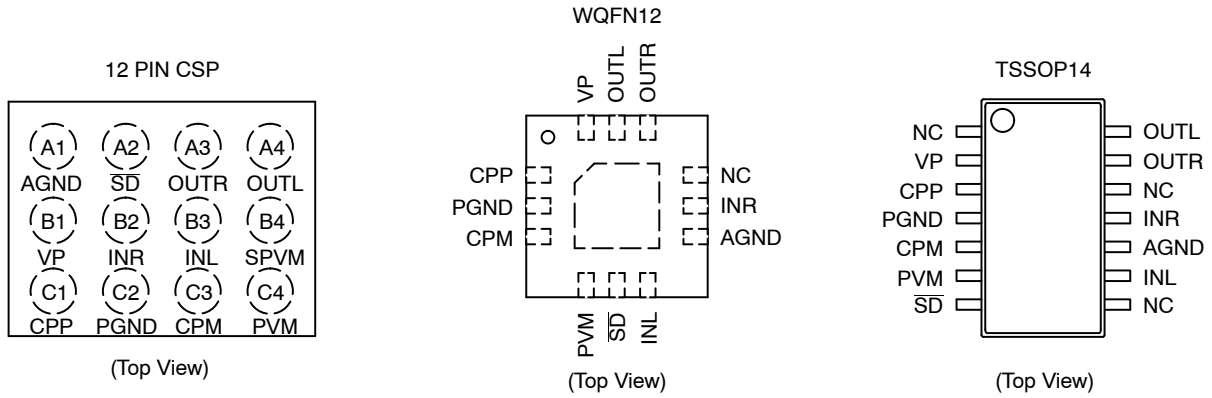


Figure 2. Pin Configurations

# NCP2811

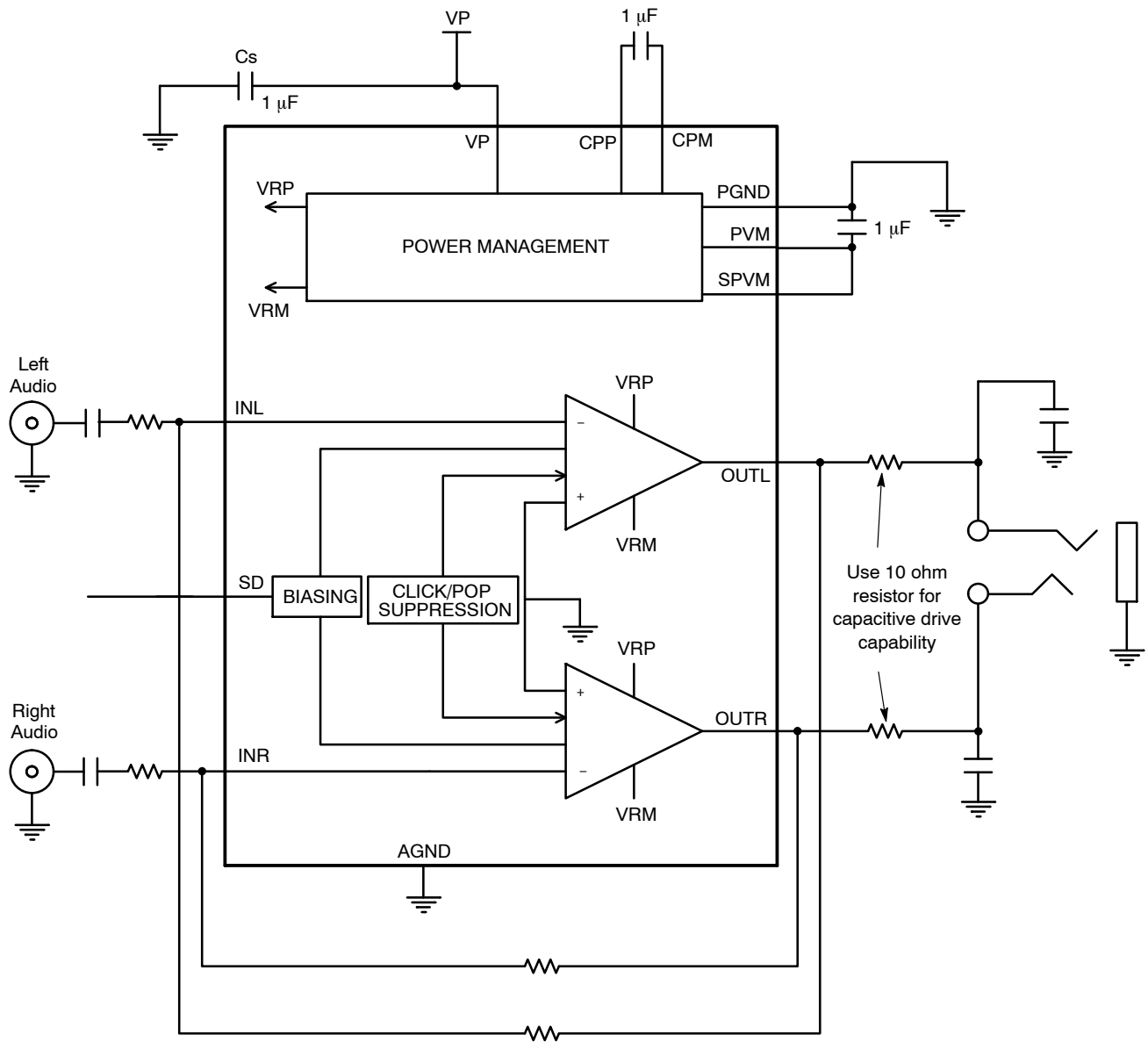
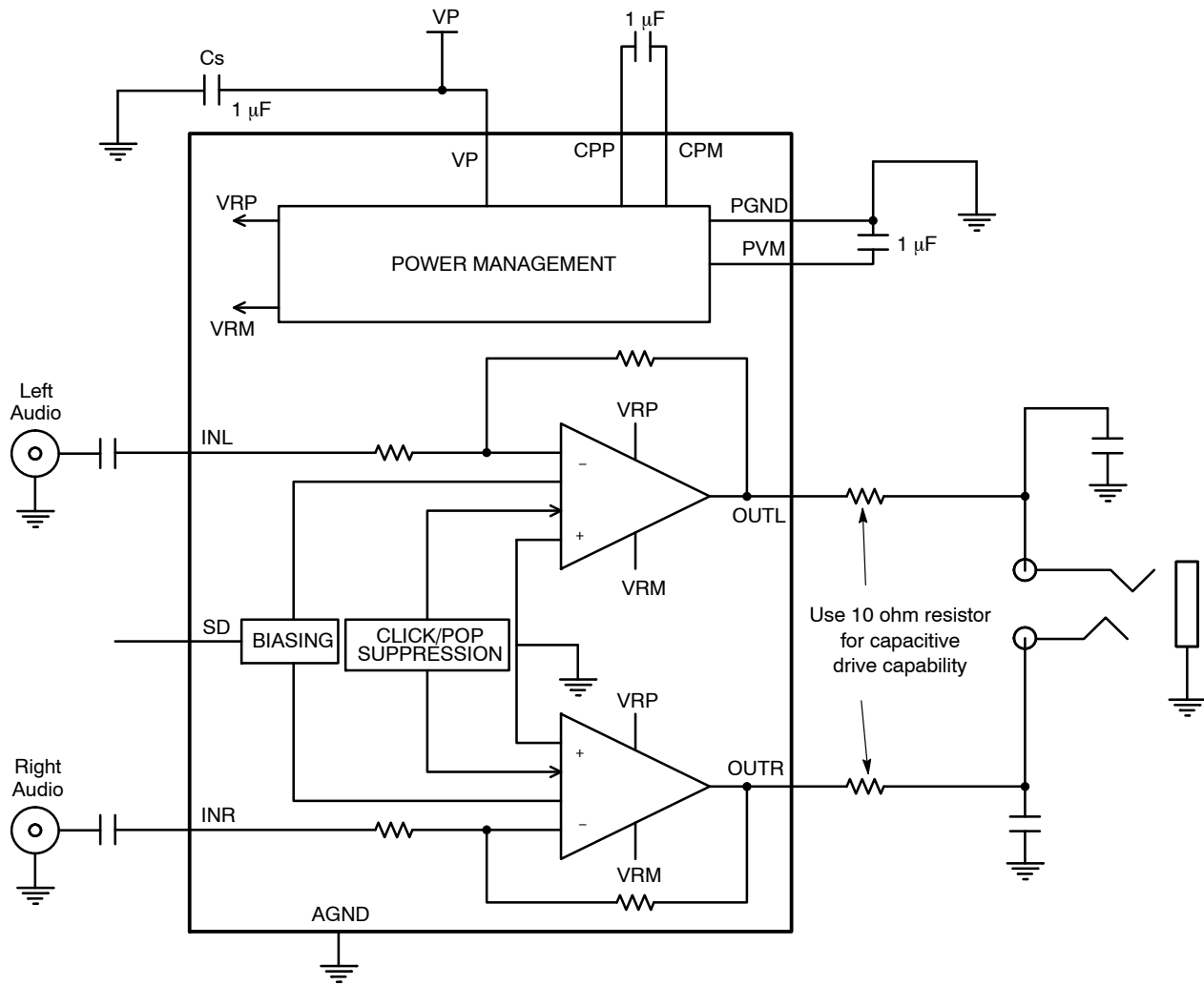


Figure 3. Typical Application Schematic version A

# NCP2811



**Figure 4. Typical Application Schematic version B**

**Table 1. PIN FUNCTION DESCRIPTION**

| PIN CSP | PIN TQFN | PIN TS-SOP | PIN NAME | TYPE         | DESCRIPTION   |
|---------|----------|------------|----------|--------------|---|
| A1      | 7        | 10         | AGND     | GROUND       | Analog ground. Connect to ground reference  |
| A2      | 5        | 7          | SD       | INPUT        | Enable activation   |
| A3      | 10       | 13         | OUTR     | OUTPUT       | Right audio channel output signal   |
| A4      | 11       | 14         | OUTL     | OUTPUT       | Left audio channel output signal  |
| B1      | 12       | 2          | VP       | POWER        | Positive supply voltage. It can be connected for example to a Lithium/Ion battery                   |
| B2      | 8        | 11         | INR      | INPUT        | Right input of the first audio source   |
| B3      | 6        | 9          | INL      | INPUT        | Left input of the first audio source  |
| B4      | -        | -          | SPVM     | POWER        | Amplifier negative power supply voltage. Connect to PVM   |
| C1      | 1        | 3          | CPP      | INPUT/OUTPUT | Charge pump flying capacitor positive terminal. A 1 μF ceramic filtering capacitor to CPM is needed |
| C2      | 2        | 4          | PGND     | GROUND       | Power ground, connect to ground reference   |
| C3      | 3        | 5          | CPM      | INPUT        | Charge pump flying capacitor negative terminal. A 1 μF ceramic filtering capacitor to CPP is needed |
| C4      | 4        | 6          | PVM      | OUTPUT       | Charge pump output. A 1 μF ceramic filtering capacitor to ground is needed                          |

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**Table 2. MAXIMUM RATINGS**

| Rating  | Symbol            | Value   | Unit |
|---|-------------------|---|------|
| AVIN, PVIN Pins: Power Supply Voltage (Note 2)                                  | V <sub>P</sub>    | - 0.3 to + 6.0  | V    |
| INL, INR Pins: Input (Note 2)<br>A version<br>B version                         | V <sub>IN</sub>   | -V <sub>P</sub> - 0.3 to V <sub>P</sub> + 0.3<br>-2 to +2 | V    |
| $\overline{SD}$ Pin: Input (Note 2)   | V <sub>YY</sub>   | -0.3 to V <sub>P</sub> + 0.3                              | V    |
| Human Body Model (HBM) ESD Rating are (Note 3)                                  | ESD HBM           | 2000  | V    |
| Machine Model (MM) ESD Rating are (Note 3)                                      | ESD MM            | 200   | V    |
| CSP 1.5 x 2.0 mm package (Notes 6 and 7)<br>Thermal Resistance Junction to Case | R <sub>θJC</sub>  | (Note 7)  | °C/W |
| Operating Ambient Temperature Range   | T <sub>A</sub>    | -40 to + 85   | °C   |
| Operating Junction Temperature Range  | T <sub>J</sub>    | -40 to + 125  | °C   |
| Maximum Junction Temperature (Note 6)   | T <sub>JMAX</sub> | + 150   | °C   |
| Storage Temperature Range   | T <sub>STG</sub>  | -65 to + 150  | °C   |
| Moisture Sensitivity (Note 5)   | MSL               | Level 1   |      |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

**Notes:**

- Maximum electrical ratings are defined as those values beyond which damage to the device may occur at T<sub>A</sub> = 25°C.
- According to JEDEC standard JESD22-A108B.
- This device series contains ESD protection and passes the following tests:  
Human Body Model (HBM) ±2.0 kV per JEDEC standard: JESD22-A114 for all pins.  
Machine Model (MM) ±200 V per JEDEC standard: JESD22-A115 for all pins.
- Latch up Current Maximum Rating: ±100 mA per JEDEC standard: JESD78 class II.
- Moisture Sensitivity Level (MSL): 1 per IPC/JEDEC standard: J-STD-020A.
- The thermal shutdown set to 150°C (typical) avoids irreversible damage on the device due to power dissipation.
- The R<sub>JA</sub> is highly dependent of the PCB Heatsink area. For example, R<sub>JA</sub> can equal 195°C/W with 50 mm<sup>2</sup> total area and also 135°C/W with 50 mm<sup>2</sup>. The bumps have the same thermal resistance and all need to be connected to optimize the power dissipation.

$$R_{\theta CA} = \frac{125 - T_A}{P_D} - R_{\theta JC}$$

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**Table 3. ELECTRICAL CHARACTERISTICS** Min & Max Limits apply for  $T_A$  between  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  and  $T_J$  up to  $+125^{\circ}\text{C}$  for  $V_{IN}$  between 2.7 V to 5.0 V (Unless otherwise noted). Typical values are referenced to  $T_A = +25^{\circ}\text{C}$  and  $V_{IN} = 3.6\text{ V}$ .

| Symbol               | Parameter                                  | Conditions   | Min   | Typ         | Max   | Unit                |
|----------------------|--|--|-------|-------------|-------|---------------------|
| $V_P$                | Operational Power Supply                   |  | 2.7   |             | 5.0   | V                   |
| $I_{DD}$             | Supply quiescent current                   | Both channels enabled  |       | 6.0         |       | mA                  |
| $I_{SD}$             | Shutdown current                           | $V_P = 2.7\text{ V to }5.0\text{ V}$   |       |             | 1     | $\mu\text{A}$       |
| $V_{OS}$             | Output offset voltage                      | $V_P = 2.7\text{ V to }5.0\text{ V}$   |       | $\pm 1$     |       | mV                  |
| $V_{IH}$             | High-Level input voltage SD pin            |  | 1.2   |             |       | V                   |
| $V_{IL}$             | Low-Level input voltage SD pin             |  |       |             | 0.4   | V                   |
| $R_{SD}$             | SD pin pull-down impedance                 |  |       | 190         |       | $\text{K}\Omega$    |
| $T_{WU}$             | Turning on time                            |  |       | 1           |       | ms                  |
| $T_{SD}$             | Thermal shutdown temperature               |  |       | 160         |       | $^{\circ}\text{C}$  |
| $V_{LP}$             | Max output swing (peak value)              | $V_P = 2.9\text{ V to }5.0\text{ V}$<br>Headset $\geq 16\ \Omega$<br>THD+N = 1%                              | 1     |             |       | $V_{RMS}$           |
| $P_O$                | Max output power (output in phase)         | $V_P = 2.7\text{V}$ , THD+N = 1%<br>Headset = $16\ \Omega$   |       | 27          |       | mW                  |
|                      |  | $V_P = 2.7\text{V}$ , THD+N = 1%<br>Headset = $32\ \Omega$   |       | 37          |       |                     |
|                      |  | $V_P = 3.6\text{V}$ , THD+N = 1%<br>Headset = $16\ \Omega$   |       | 90          |       |                     |
|                      |  | $V_P = 3.6\text{V}$ , THD+N = 1%<br>Headset = $32\ \Omega$   |       | 64          |       |                     |
|                      |  | $V_P = 5.0\text{V}$ , THD+N = 1%<br>Headset = $16\ \Omega$   |       | 110         |       |                     |
|                      |  | $V_P = 5.0\text{V}$ , THD+N = 1%<br>Headset = $32\ \Omega$   |       | 64          |       |                     |
|                      | Crosstalk (Note 8)                         | Headset $\geq 16\ \Omega$  |       | -80         | -60   | dB                  |
| PSRR                 | Power supply rejection ratio (Note 8)      | $V_P = 2.7\text{ V to }5.0\text{ V}$<br>Input shorted to ground<br>$F = 217\text{ Hz}$<br>$F = 1\text{ kHz}$ |       | -106<br>-95 |       | dB                  |
| THD+N                | Total harmonic distortion + noise (Note 8) | Headset = $16\ \Omega$<br>$P_{OUT} = 25\text{ mW}$   |       | 0.01        |       | %                   |
| $V_N$                | Output noise voltage (Note 8)              | A-Weighting filter   |       | 7           |       | $\mu\text{V}_{RMS}$ |
| $Z_{IN}$             | Input impedance                            | B version only   |       | 20          |       | $\text{K}\Omega$    |
| $Z_{SD}$             | Output impedance in shutdown mode          |  |       | 10          |       | $\text{K}\Omega$    |
| UVLO                 | UVLO threshold                             | Falling edge   |       | 2.3         |       | V                   |
| UVLO <sub>HYST</sub> | UVLO hysteresis                            |  |       | 100         |       | mV                  |
| $A_v$                | Voltage Gain                               | B version only   | -1.53 | -1.5        | -1.48 | V/V                 |

8. Guaranteed by design and characterized.

TYPICAL OPERATING CHARACTERISTICS

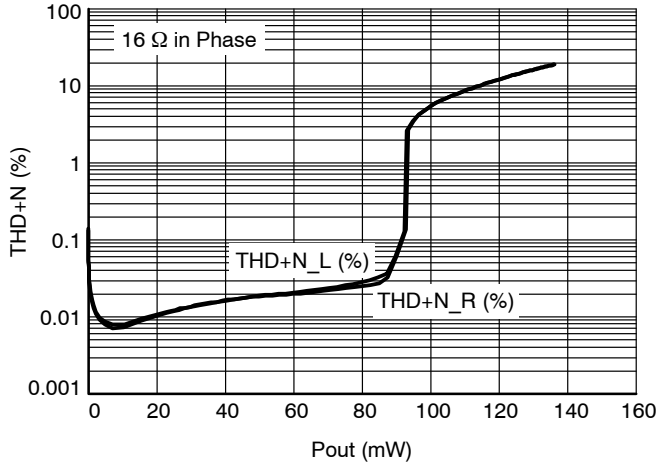


Figure 5. THD+N vs. Pout @ Vp = 3.6 V

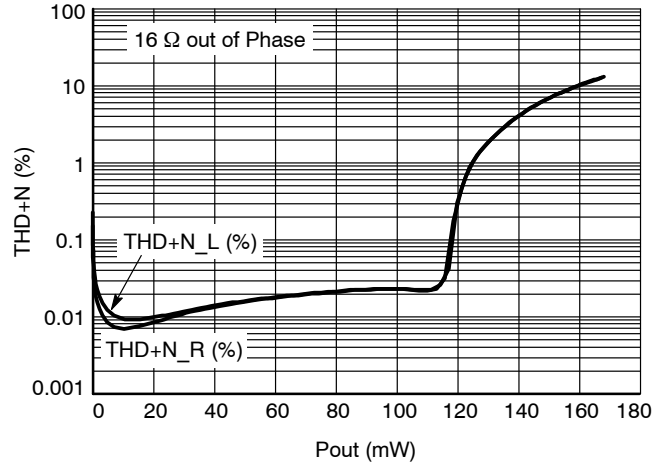


Figure 6. THD+N vs. Pout @ Vp = 3.6 V

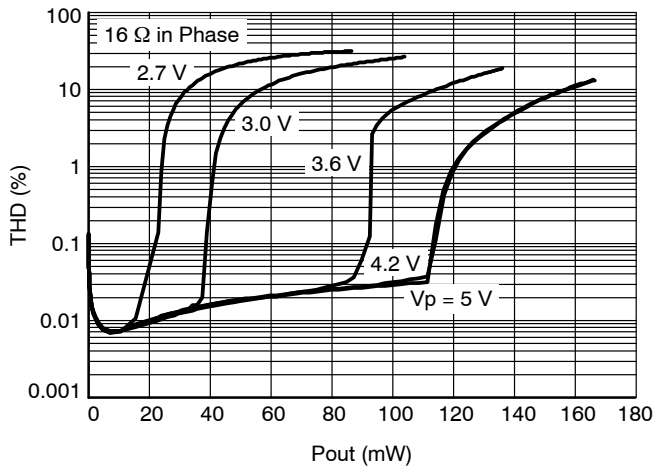


Figure 7. THD+N vs. Pout LEFT

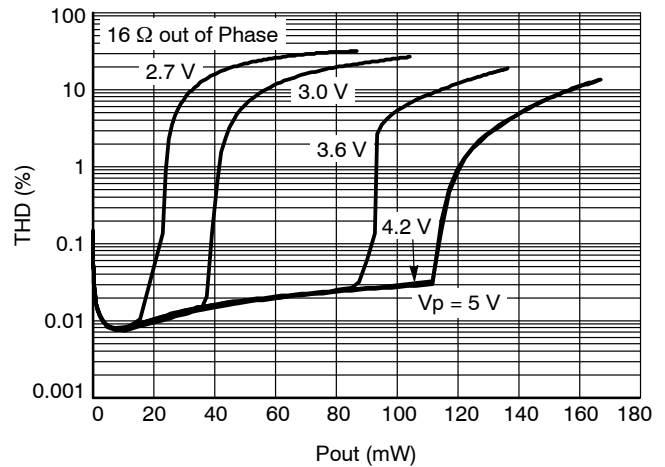


Figure 8. THD+N vs. Pout RIGHT

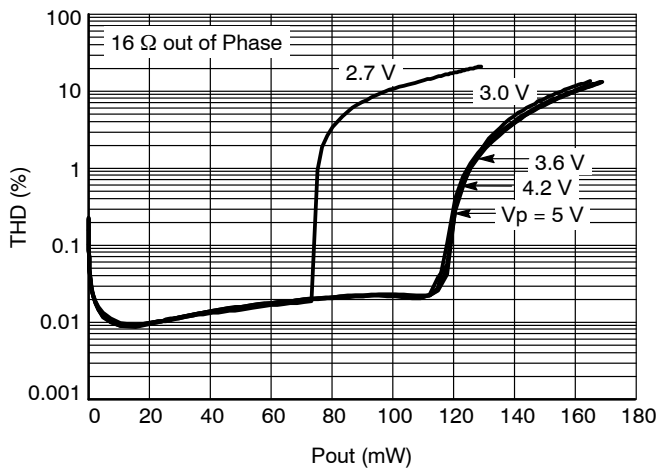


Figure 9. THD+N vs. Pout LEFT

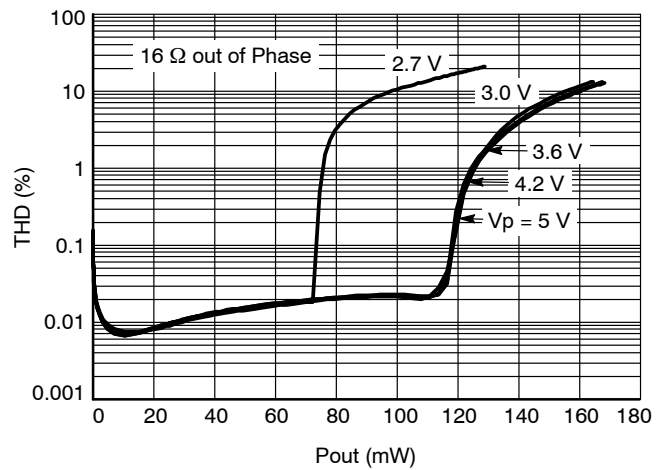


Figure 10. THD+N vs. Pout RIGHT

TYPICAL OPERATING CHARACTERISTICS

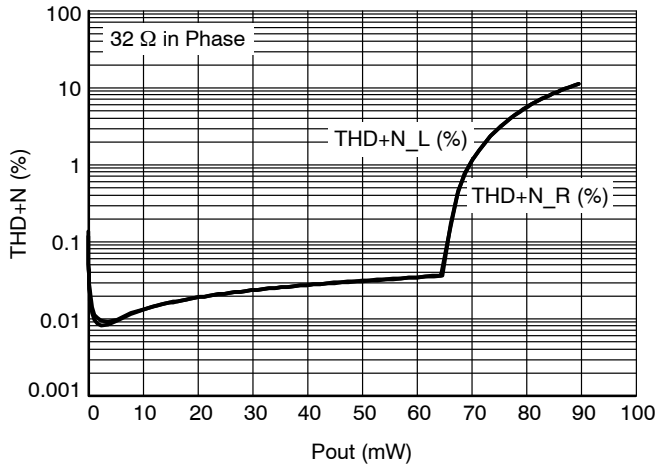


Figure 11. THD+N vs. Pout @ Vp = 3.6 V

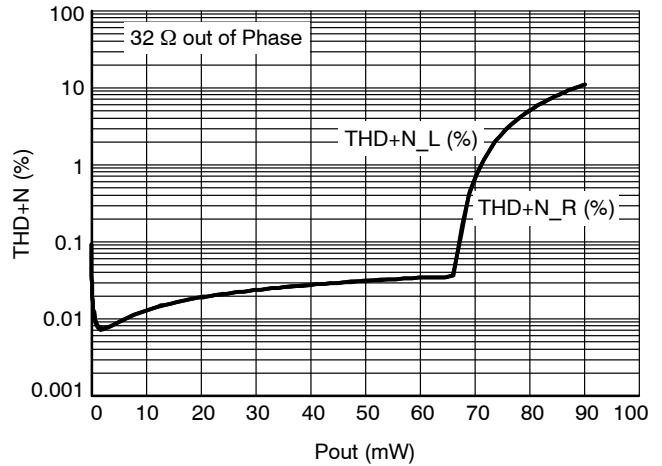


Figure 12. THD+N vs. Pout @ Vp = 3.6 V

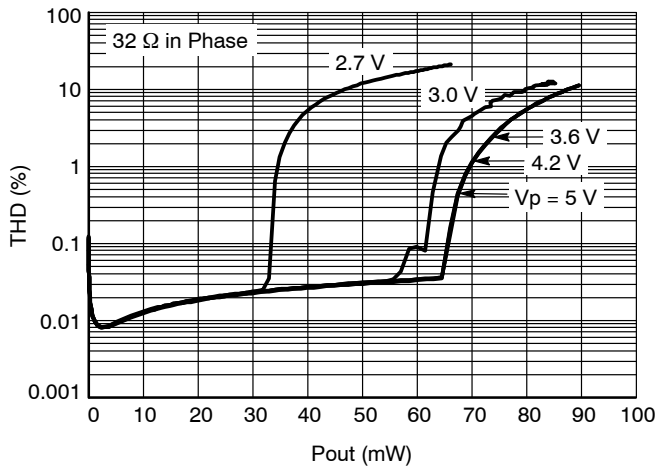


Figure 13. THD+N vs. Pout LEFT

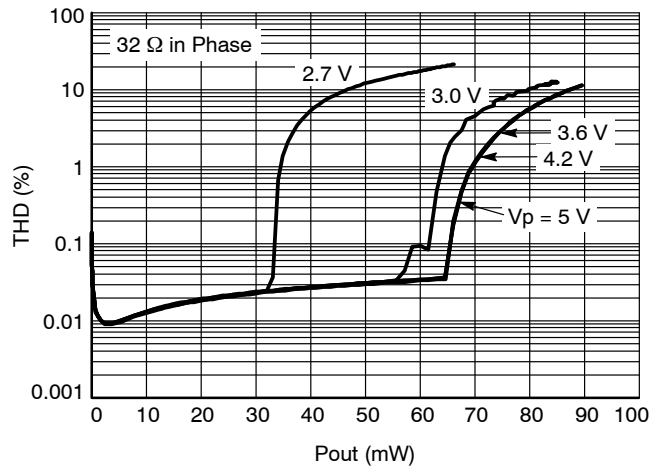


Figure 14. THD+N vs. Pout RIGHT

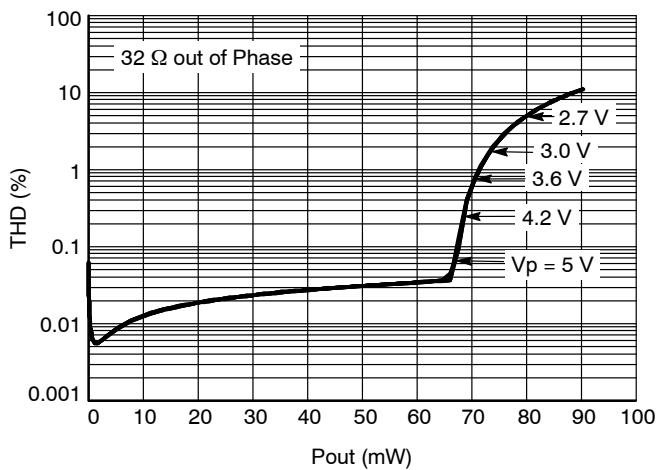


Figure 15. THD+N vs. Pout LEFT

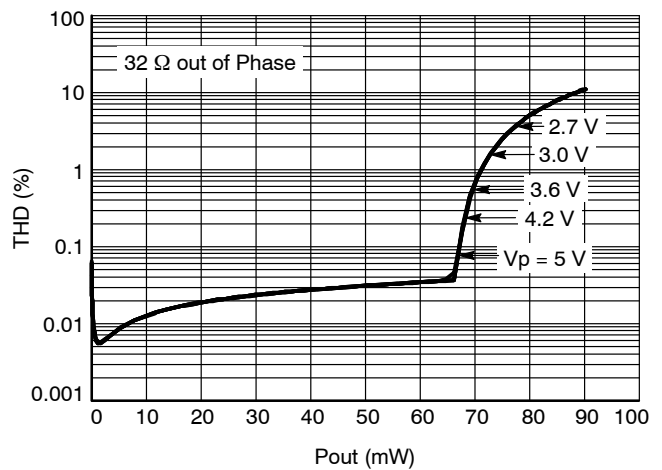


Figure 16. THD+N vs. Pout RIGHT

TYPICAL OPERATING CHARACTERISTICS

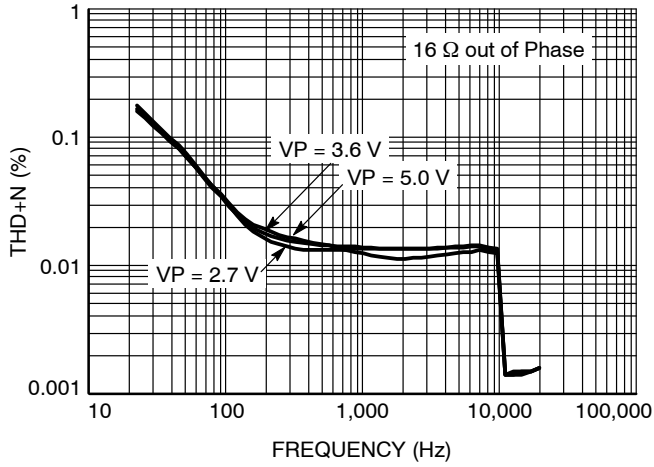


Figure 17. THD vs. Frequency LEFT @ Pout = 32 mW

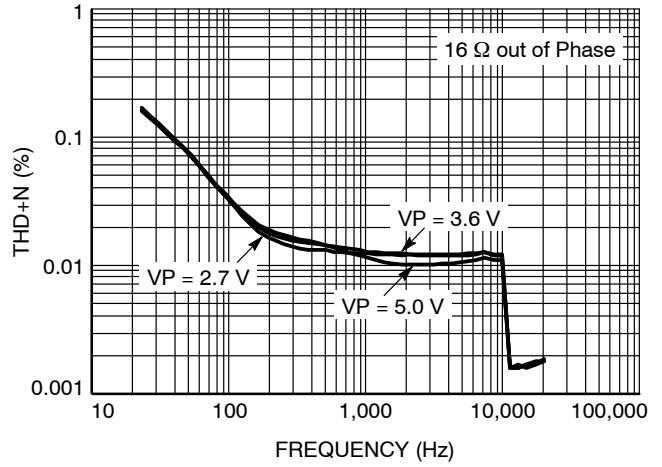


Figure 18. THD vs. Frequency RIGHT @ Pout = 32 mW

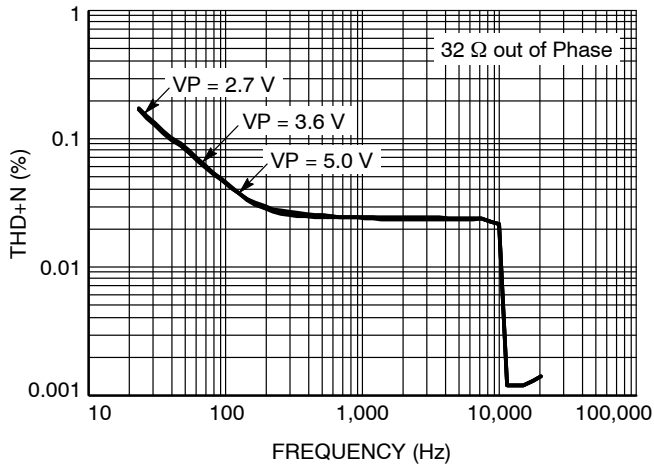


Figure 19. THD vs. Frequency LEFT @ Pout = 32 mW

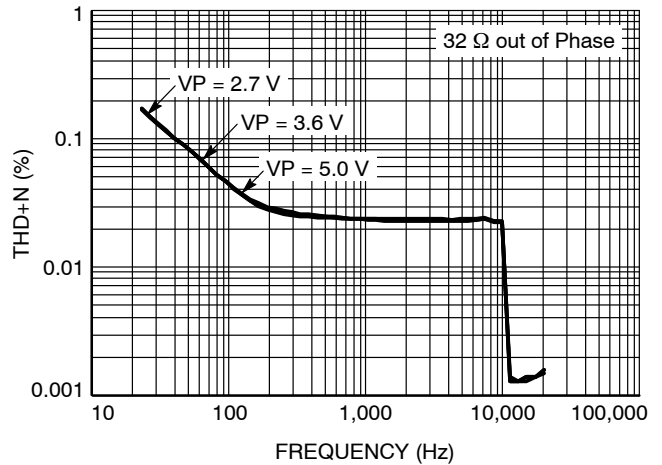


Figure 20. THD vs. Frequency RIGHT @ Pout = 32 mW

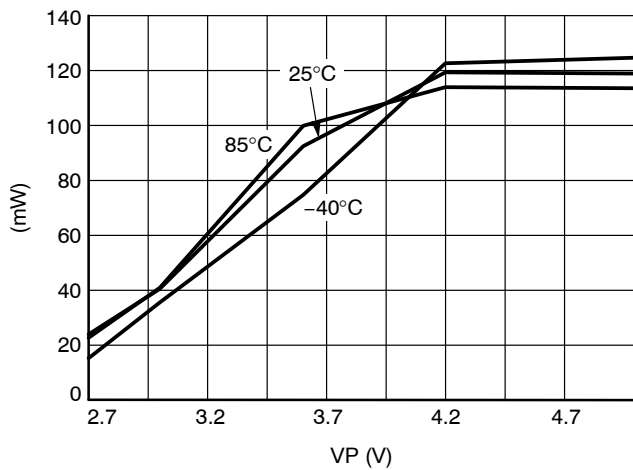


Figure 21. Maximum Output Power LEFT vs. VP (THD+N < 1%)

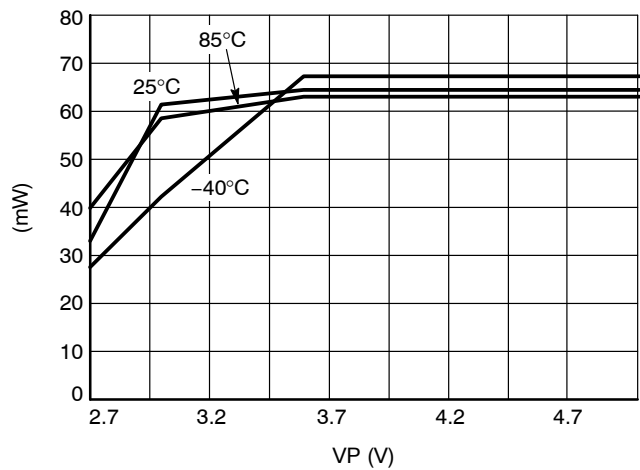


Figure 22. Maximum Output Power LEFT vs. VP (THD+N < 0.1%)

# NCP2811

## TYPICAL OPERATING CHARACTERISTICS

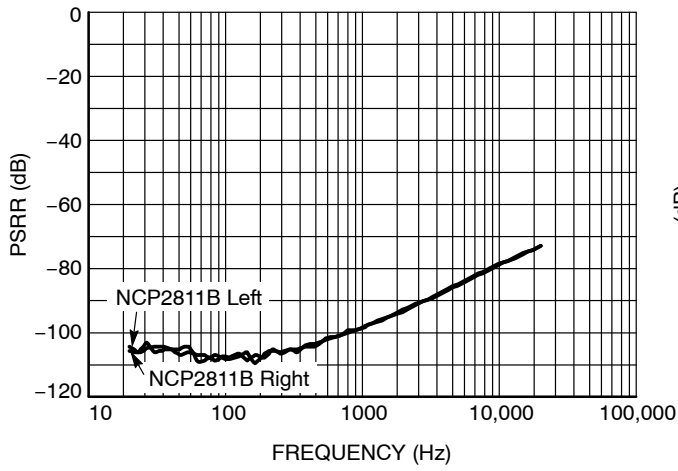


Figure 23. PSRR at  $V_p = 3.6$  V

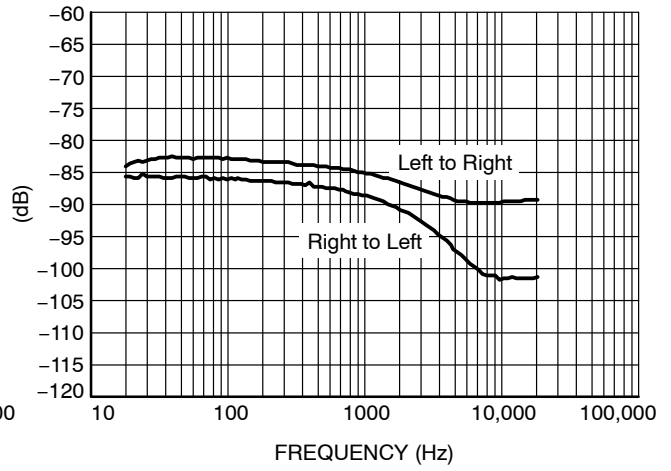


Figure 24. Crosstalk vs. Frequency  
@  $V_p = 3.6$  V

DETAIL OPERATING DESCRIPTION

**Detailed Descriptions**

The NCP2811 is a stereo headphone amplifier with a true ground architecture. This architecture eliminates the need to use 2 external big capacitors required by conventional headphone amplifier.

The structure of the NCP2811 is basically composed of 2 true ground amplifiers, an UVLO, a short circuit protection and also a thermal shutdown. A special circuitry is embedded to eliminate any pop and click noise that occurs during turn on and turn off time. The A version has an external gain selectable by two resistor, B version has a gain of 1.5 V/V.

**NOCAP™**

NOCAP™ is a patented architecture which requires only 2 small ceramic capacitors. It generates a symmetrical positive and negative voltage and it allows the output of the amplifiers to be biased around the ground.

**Current Limit Protection Circuit**

The NCP2811 embed a protection circuitry against short to ground. When an output is shorted to GND and when a signal appears at the input, the current is limited to 300 mA.

**Thermal Overload Protection**

Internal amplifiers are switched off when the temperature exceed 160°C, and will be switch on again when the temperature decrease below 140°C.

**Under Voltage Lockout**

When the battery voltage decreases below 2.3 V, the amplifiers are turned off. The hysteresis to turn on it again is 100 mV.

**Pop and Click Suppression Circuitry**

The NCP2811 includes a special circuitry to eliminate any pop and click noise during turn on and turn off time. Basic amplifier creates an offset during these transitions at the output which give a parasitic noise called “pop and click noise”. The NCP2811 eliminates this problem.

**Gain Setting Resistor Selection (R<sub>in</sub> & R<sub>f</sub>, A version only)**

R<sub>in</sub> and R<sub>f</sub> set the closed loop gain of the amplifier. A low gain configuration (close to 1) minimizes the THD + noise values and maximizes the signal to noise ratio.

A closed loop gain in the range of 1 to 10 is recommended to optimize overall system performance.

The formula to calculate the gain is:

$$A_v = - \frac{R_f}{R_{in}}$$

**Input Capacitor Selection**

The input coupling capacitor blocks the DC voltage at the amplifier input terminal. This capacitor creates a high-pass

filter with R<sub>in</sub> (externally selectable for A version, 20 kΩ for B version).

The size of the capacitor must be large enough to couple in low frequencies without severe attenuation in the audio bandwidth (20 Hz – 20 kHz).

The cut off frequency for the input high-pass filter is:

$$F_c = \frac{1}{2\pi R_{in} C_{in}}$$

A F<sub>c</sub> < 20 Hz is recommended.

**Charge Pump Capacitor Selection**

Use ceramic capacitor with low ESR for better performances. X5R / X7R capacitor is recommended.

The flying capacitor (C2) serves to transfer charge during the generation of the negative voltage.

The CPVM capacitor (C3) must be equal at least to the CFly capacitor to allow maximum transfer charge. The CPVM value must not exceed 1 μF. Higher capacitor value can damage the part.

Table 4 suggests typical value and manufacturer:

**Table 4.**

| Value | Reference        | Package | Manufacturer |
|-------|------------------|---------|--------------|
| 1 μF  | C1005X5R0J105K   | 0402    | TDK          |
| 1 μF  | GRM155R60J105K19 | 0402    | Murata       |

Lower value of capacitors can be used but the maximum output power is reduced and the device may not operate to specifications.

**Power Supply Decoupling Capacitor (C1)**

The NCP2811 is a True Ground amplifier which requires the adequate decoupling capacitor to reduce noise and THD+N. Use X5R / X7R ceramic capacitor and place it closed to the CPVDD pin. A value of 1 μF is recommended.

**Shutdown Function**

The device enters in shutdown mode when shutdown signal is low. During the shutdown mode, the DC quiescent current of the circuit does not exceed 500 nA. In this configuration, the output impedance is 10 kΩ on each output.

**Output Resistor for Capacitive Drive Capability**

Under normal operation, NCP2811 maximum direct capacitive load is in the 80 pF range. If, for any reason, high value capacitive loads should be connected to NCP2811 outputs, an additional 10 Ω resistor should be placed between the NCP2811 output and the capacitive load to ensure amplifier stability.

**Layout Recommendation**

Connect C1 as close as possible of the V<sub>p</sub> pin.

Connect C2 and C3 as close as possible of the NCP2811.

Route audio signal and AGND far from V<sub>p</sub>, CPP, CPM, PVM and PGND to avoid any perturbation due to the switching.

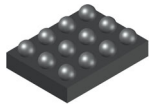
# NCP2811

**Table 5. ORDERING INFORMATION**

| Device         | Package  | Shipping†        |
|----------------|--|------------------|
| NCP2811ADTBR2G | TSSOP-14<br>(Pb-Free)                                    | 2500/Tape & Reel |
| NCP2811BDTBR2G | TSSOP-14<br>(Pb-Free)                                    | 2500/Tape & Reel |
| NCP2811AFCT1G  | Flip-Chip 12<br>(Pb-Free)                                | 3000/Tape & Reel |
| NCP2811BFCT1G  | Flip-Chip 12<br>(Pb-Free)                                | 3000/Tape & Reel |
| NCP2811BFCCT1G | Flip-Chip 12<br>(Backside Laminate Coating)<br>(Pb-Free) | 3000/Tape & Reel |
| NCP2811AMTTXG  | WQFN12<br>(Pb-Free)                                      | 3000/Tape & Reel |
| NCP2811BMTTXG  | WQFN12<br>(Pb-Free)                                      | 3000/Tape & Reel |

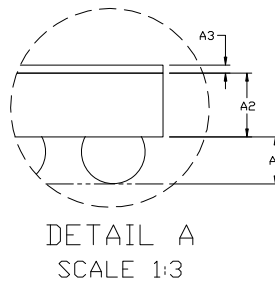
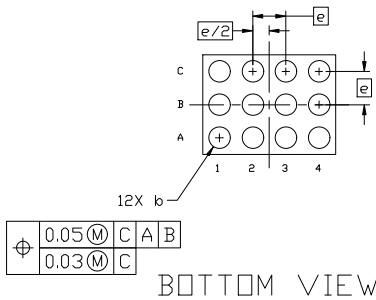
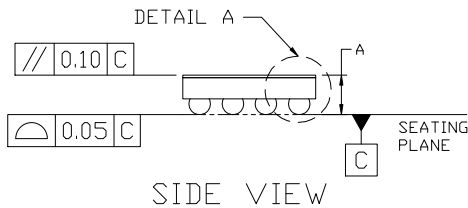
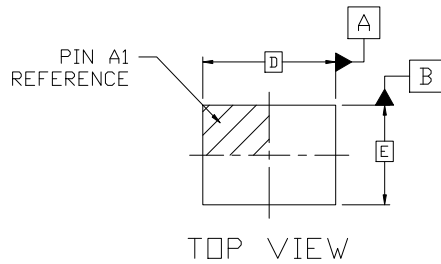
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



**WLCSP12 2.00x1.50x0.596**  
CASE 499AZ  
ISSUE A

DATE 03 JUN 2022

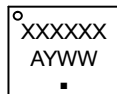


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER PARALLEL TO DATUM C.
4. COPLANARITY APPLIES TO THE SPHERICAL CROWNS OF THE SOLDER BALLS.
5. DATUM C, THE SEATING PLANE, IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.

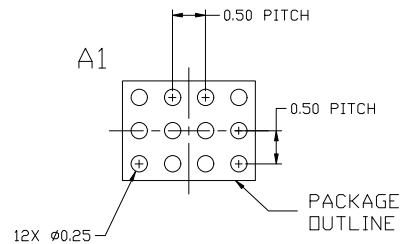
| DIM | MILLIMETERS |       |       |
|-----|-------------|-------|-------|
|     | MIN.        | NOM.  | MAX.  |
| A   | 0.541       | 0.596 | 0.651 |
| A1  | 0.206       | 0.236 | 0.266 |
| A2  | 0.295       | 0.320 | 0.345 |
| A3  | 0.04 BSC    |       |       |
| b   | 0.289       | 0.319 | 0.349 |
| D   | 2.00 BSC    |       |       |
| E   | 1.50 BSC    |       |       |
| e   | 0.50 BSC    |       |       |

**GENERIC MARKING DIAGRAM\***



- XXXX = Specific Device Code
- A = Assembly Location
- Y = Year
- WW = Work Week
- = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



**RECOMMENDED MOUNTING FOOTPRINT\***

\* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

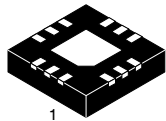
|                         |                                |  |
|-------------------------|--------------------------------|--|
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| <b>DESCRIPTION:</b>     | <b>WLCSP12 2.00x1.50x0.596</b> | <b>PAGE 1 OF 1</b>   |

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# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

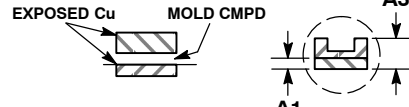
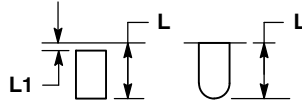
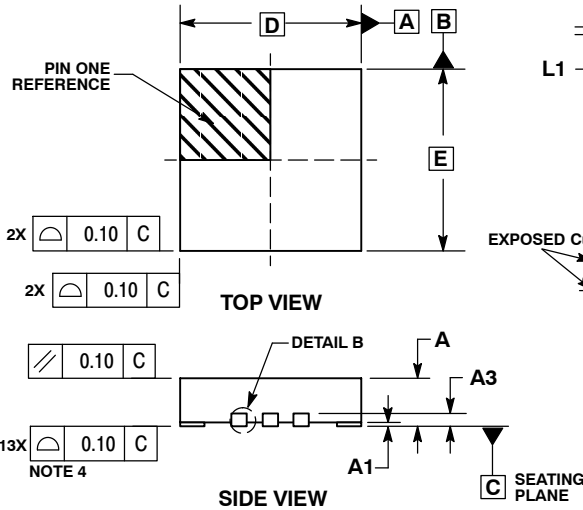
ON Semiconductor®



SCALE 4:1

WQFN12 3x3, 0.5P  
CASE 510AH-01  
ISSUE O

DATE 20 JAN 2009

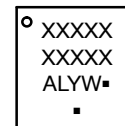


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

| MILLIMETERS |          |      |
|-------------|----------|------|
| DIM         | MIN      | MAX  |
| A           | 0.65     | 0.85 |
| A1          | 0.00     | 0.05 |
| A3          | 0.22     | REF  |
| b           | 0.20     | 0.30 |
| D           | 3.00 BSC |      |
| D2          | 1.30     | 1.50 |
| E           | 3.00 BSC |      |
| E2          | 1.30     | 1.50 |
| e           | 0.50 BSC |      |
| K           | 0.20     | ---  |
| L           | 0.30     | 0.50 |
| L1          | 0.00     | 0.15 |

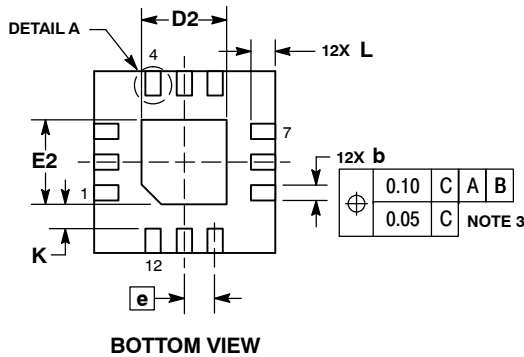
**GENERIC MARKING DIAGRAM\***



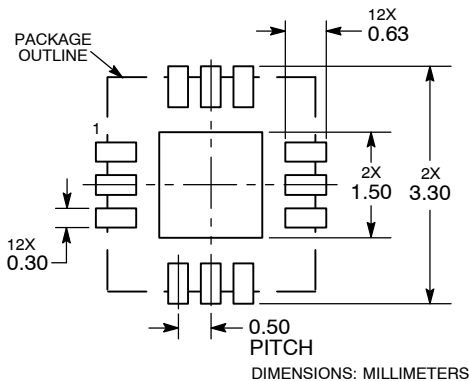
- XXXXX = Specific Device Code
- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.



**SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

|                         |                           |  |
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| <b>NEW STANDARD:</b>    |                           |  |
| <b>DESCRIPTION:</b>     | WQFN12, 3X3, 0.5P         | <b>PAGE 1 OF 2</b>   |



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